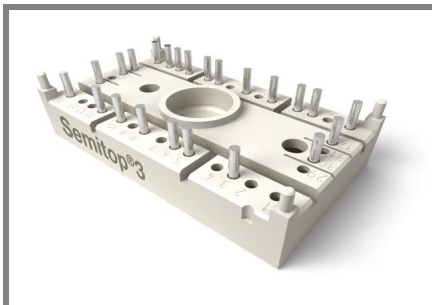


SK80GB125T



SEMITOP[®] 3

IGBT Module

SK80GB125T

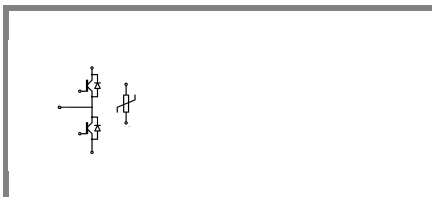
Preliminary Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonding Aluminium Nitride ceramic (DBC)
- High short circuit capability
- Low tail current with low temperature dependence

Typical Applications

- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

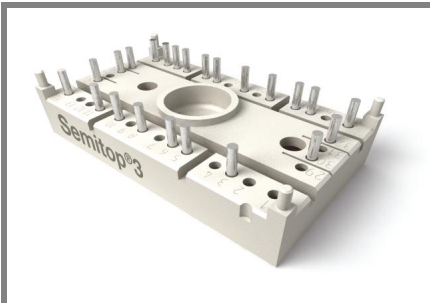


GB - T

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified		
Symbol	Conditions	Values		Units
IGBT				
V_{CES}	$T_j = 25\text{ °C}$	1200		V
I_C	$T_j = 125\text{ °C}$	$T_s = 25\text{ °C}$	85	A
		$T_s = 80\text{ °C}$	55	A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	150		A
V_{GES}		± 20		V
t_{psc}	$V_{CC} = 300\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125\text{ °C}$ $V_{CES} < 600\text{ V}$	10		μs
Inverse Diode				
I_F	$T_j = 150\text{ °C}$	$T_s = 25\text{ °C}$	90	A
		$T_s = 80\text{ °C}$	60	A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$			A
I_{FSM}	$t_p = 10\text{ ms}; \text{half sine wave } T_j = 150\text{ °C}$	550		A
Module				
$I_{t(RMS)}$				A
T_{vj}		-40 ... +150		$^{\circ}\text{C}$
T_{stg}		-40 ... +125		$^{\circ}\text{C}$
V_{isol}	AC, 1 min.	2500		V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified				
Symbol	Conditions	min.	typ.	max.	Units	
IGBT						
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 3\text{ mA}$	4,5	5,5	6,5	V	
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES} \quad T_j = 25\text{ °C}$			0,01	mA	
I_{GES}	$V_{CE} = 0\text{ V}, V_{GE} = 20\text{ V} \quad T_j = 25\text{ °C}$			480	nA	
V_{CE0}		$T_j = 25\text{ °C}$	1,4	1,9	V	
		$T_j = 125\text{ °C}$	1,7	2,2	V	
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$			18,6	$\text{m}\Omega$
		$T_j = 125\text{ °C}$			20	$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 75\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	3,2	3,3	V	
		$T_j = 125\text{ °C}_{chiplev.}$	3,85	3,7	V	
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V} \quad f = 1\text{ MHz}$			5,1	nF	
C_{oes}				0,72	nF	
C_{res}				0,38	nF	
$t_{d(on)}$	$R_{Gon} = 8,2\ \Omega$	$V_{CC} = 600\text{ V}$ $I_{Cnom} = 80\text{ A}$			180	ns
t_r					110	ns
E_{on}	$R_{Goff} = 8,2\ \Omega$	$T_j = 125\text{ °C}$ $V_{GE} = \pm 15\text{ V}$			9,9	mJ
$t_{d(off)}$					358	ns
t_f					26	ns
E_{off}					5	mJ
$R_{th(j-s)}$	per IGBT			0,32	K/W	

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IGBT Module

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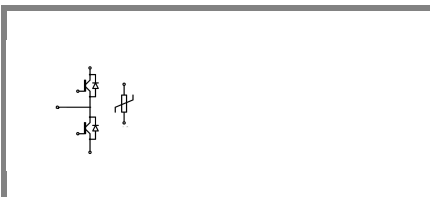
Preliminary Data

Features

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Typical Applications

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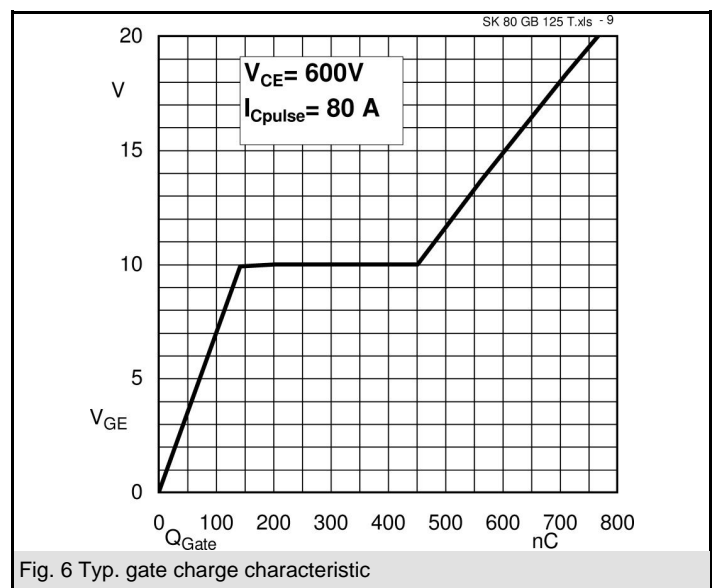
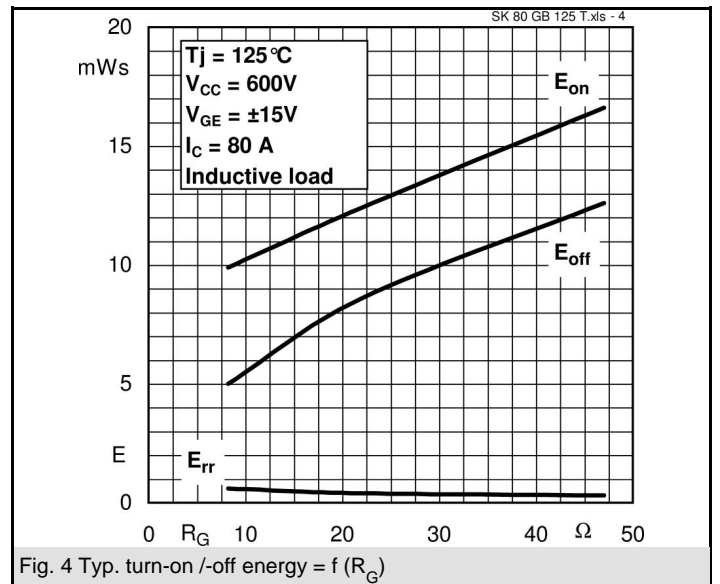
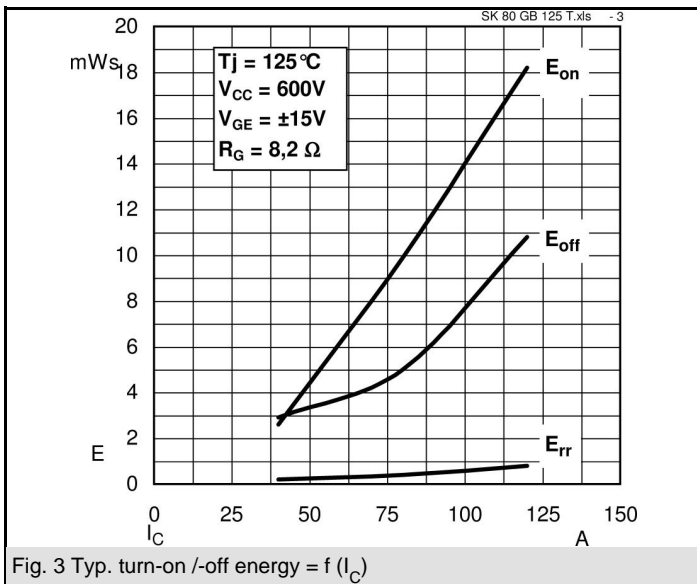
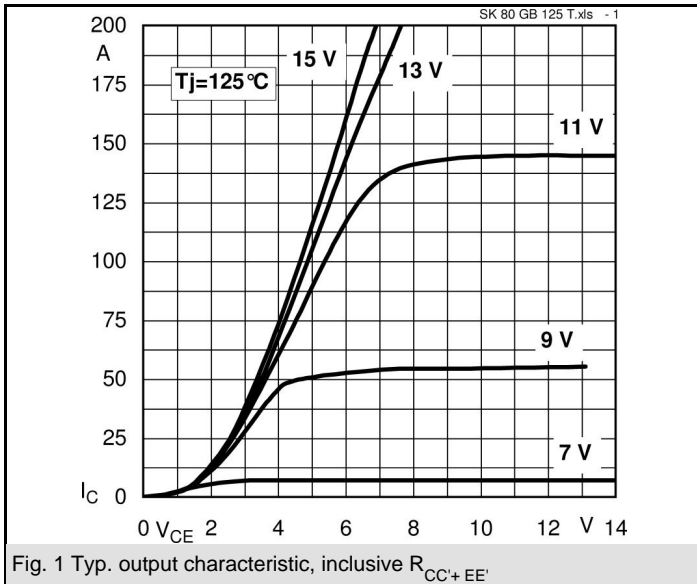
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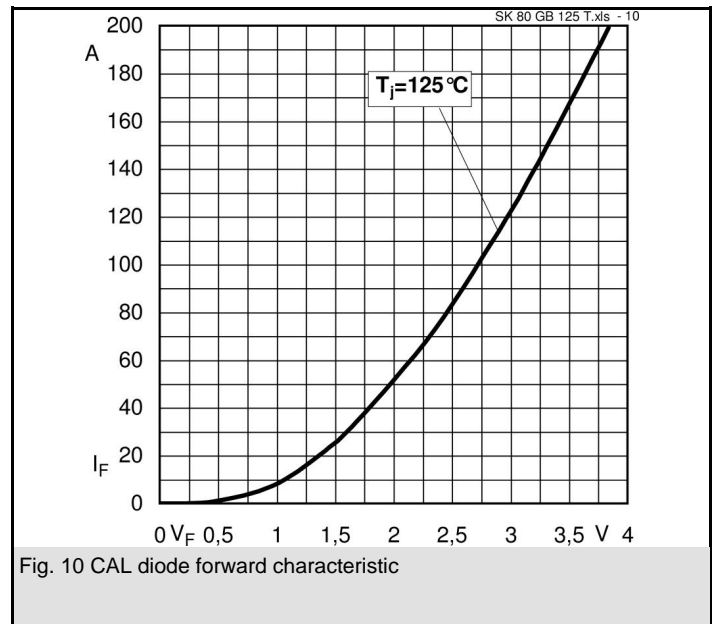
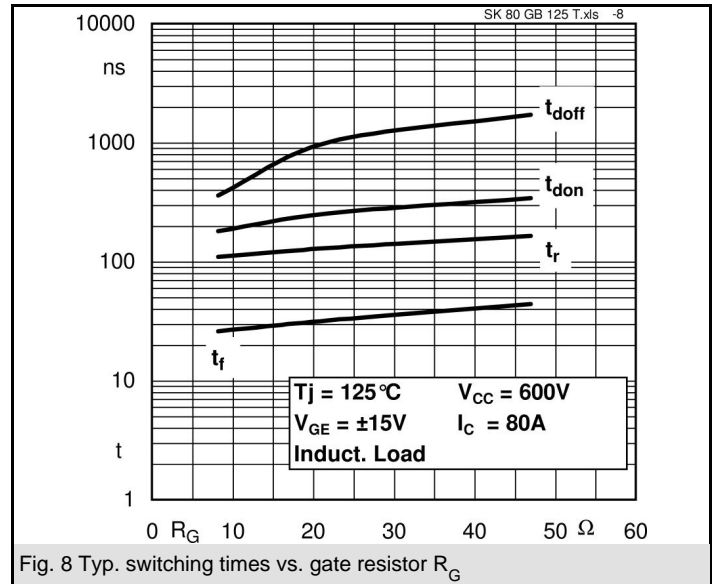
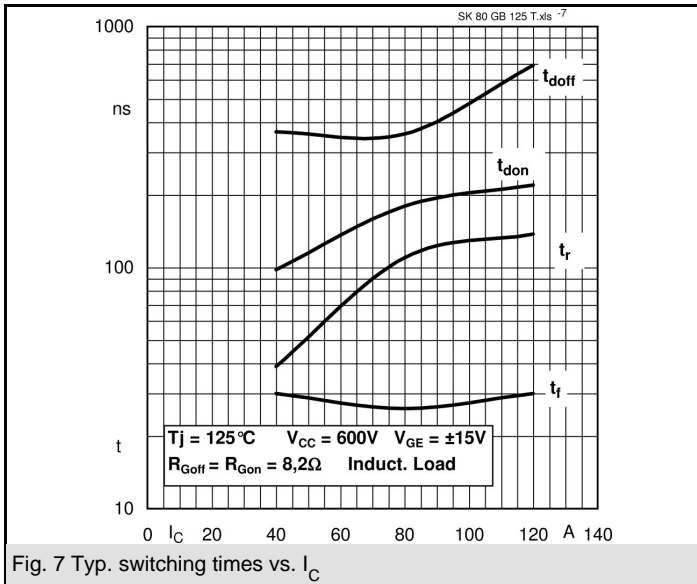
Characteristics

Symbol	Conditions	min.	typ.	max.	Units
Inverse Diode					
$V_F = V_{EC}$	$I_{Fnom} = 55 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$	2		V
		$T_j = 150 \text{ }^\circ\text{C}_{\text{chiplev.}}$	1,8		V
V_{F0}		$T_j = 25 \text{ }^\circ\text{C}$			V
		$T_j = 125 \text{ }^\circ\text{C}$	1,2		V
r_F		$T_j = 25 \text{ }^\circ\text{C}$			mΩ
		$T_j = 125 \text{ }^\circ\text{C}$	11		mΩ
I_{RRM}	$I_{Fnom} = 50 \text{ A}$	$T_j = 125 \text{ }^\circ\text{C}$	40		A
Q_{rr}	$di/dt = -800 \text{ A}/\mu\text{s}$		8		μC
E_{rr}	$V_{CC} = 600\text{V}$		1		mJ
$R_{th(j-s)D}$	per diode			0,65	K/W
M_s	to heat sink	2,25		2,5	Nm
w			30		g
Temperature sensor					
R_{100}	$T_s = 100^\circ\text{C}$ ($R_{25} = 5\text{k}\Omega$)		493±5%		Ω

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

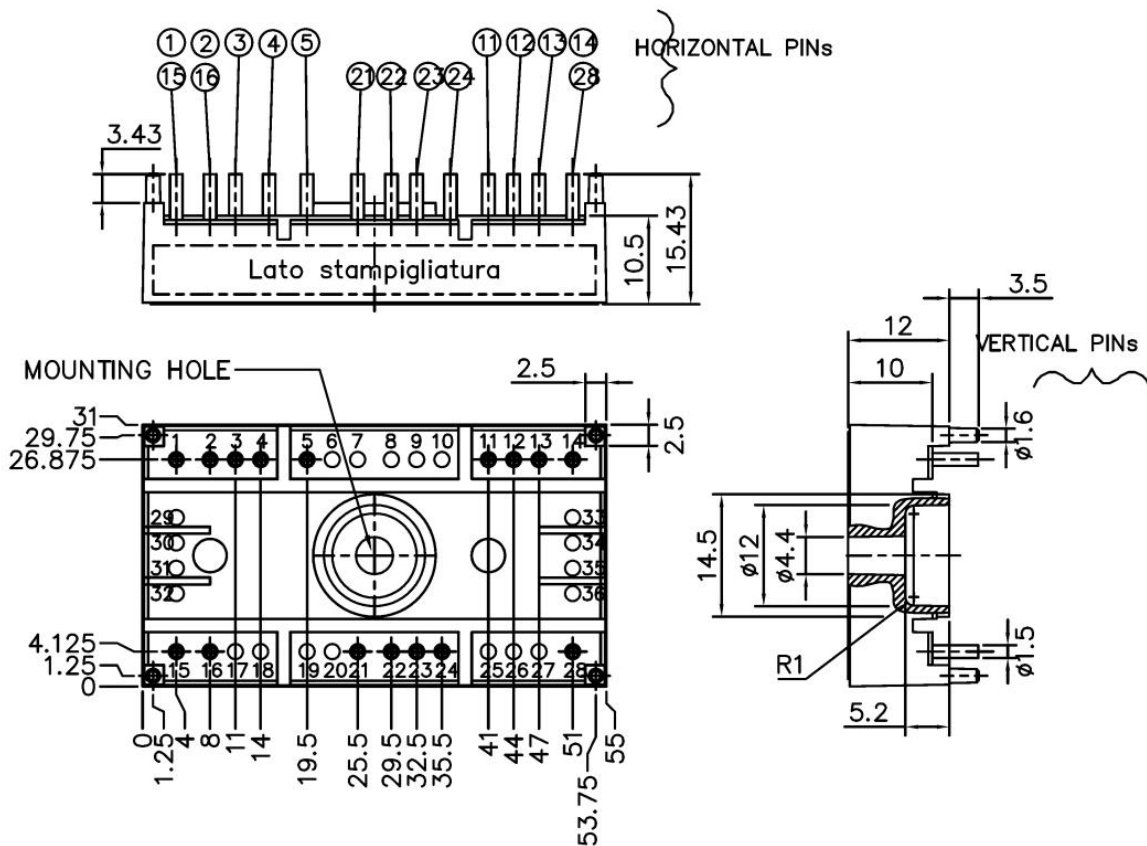




SK80GB125T

UL Recognized
File no. E 63 532

Dimensions in mm



Case T73 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)

